

## Symbol LED in 2 x 5 mm Flat Tinted Top-Diffused Package

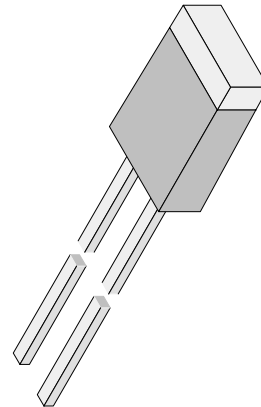
Color	Type	Technology	Angle of Half Intensity $\pm\varphi$
Red	TLSH210.	GaAsP on GaP	50°
Yellow	TLSY210.	GaAsP on GaP	50°
Green	TLSG210.	GaP on GaP	50°

### Description

This series was developed for use as compact surface display.

It is housed in a 2x5 mm rectangular molded package. This device has a flat tinted, top diffused package for uniform brightness when used in panels.

The symbol LEDs are available in three bright colors: high efficiency red, yellow and green.



96 11498

### Features

- Choice of three bright colors
- Uniform illumination
- Luminous intensity selected into groups
- Suitable for DC and pulse operation
- Flat light emitting surface
- Direct symbol indication is possible
- Yellow and green color categorized
- Wide viewing angle

### Applications

Status lights  
Background illumination  
Maintenance lights  
Indicator of audio and visual equipment  
Off / On indicator  
Readout lights  
Legend lights  
Illumination of moving boards

### Absolute Maximum Ratings

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

TLSH210., TLSY210., TLSG210.,

Parameter	Test Conditions	Symbol	Value	Unit
Reverse voltage		$V_R$	6	V
DC forward current		$I_F$	30	mA
Surge forward current	$t_p \leq 10 \mu\text{s}$	$I_{FSM}$	1	A
Power dissipation	$T_{amb} \leq 65^{\circ}\text{C}$	$P_V$	100	mW
Junction temperature		$T_j$	100	$^{\circ}\text{C}$
Storage temperature range		$T_{stg}$	-55 to +100	$^{\circ}\text{C}$
Soldering temperature	$t \leq 5 \text{ s}$ , 2 mm from body	$T_{sd}$	260	$^{\circ}\text{C}$
Thermal resistance junction/ambient		$R_{thJA}$	350	K/W

### Optical and Electrical Characteristics

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

Red (TLSH210.)

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity	$I_F = 10 \text{ mA}$ , $I_{Vmin}/I_{Vmax} \geq 0.5$	TLSH2100	$I_V$	0.63	2		mcd
		TLSH2101	$I_V$	1	2.5		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$		640		nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		650		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 50$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0$ , $f = 1 \text{ MHz}$		$C_j$		50		pF

Yellow (TLSY210.)

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity	$I_F = 10 \text{ mA}$ , $I_{Vmin}/I_{Vmax} \geq 0.5$	TLSY2100	$I_V$	0.63	2		mcd
		TLSY2101	$I_V$	1	2		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	581		594	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		585		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 50$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0$ , $f = 1 \text{ MHz}$		$C_j$		50		pF



**Green (TLSG210.)**

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity	$I_F = 10 \text{ mA}$ , $I_{V\min}/I_{V\max} \geq 0.5$	TLSG2100	$I_V$	1	2		mcd
		TLSG2101	$I_V$	1.6	2.5		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	562		575	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		565		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 50$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \text{ }\mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0$ , $f = 1 \text{ MHz}$		$C_j$		50		pF

**Typical Characteristics** ( $T_{\text{amb}} = 25^\circ\text{C}$ , unless otherwise specified)

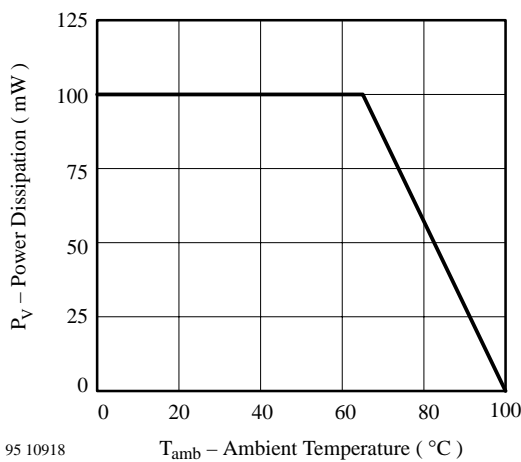


Figure 1 Power Dissipation vs. Ambient Temperature

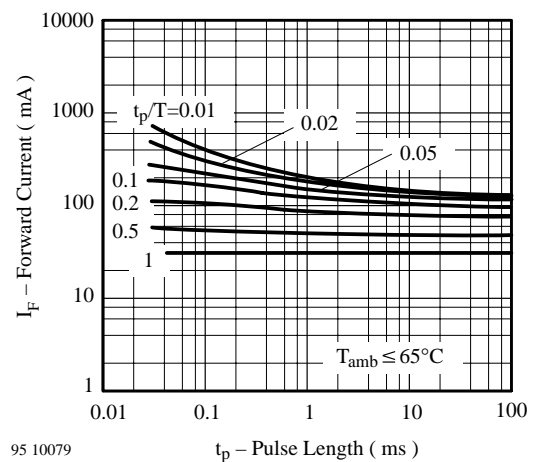


Figure 3 Forward Current vs. Pulse Length

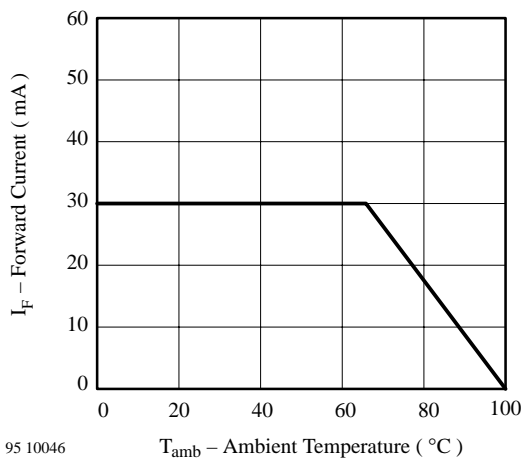


Figure 2 Forward Current vs. Ambient Temperature

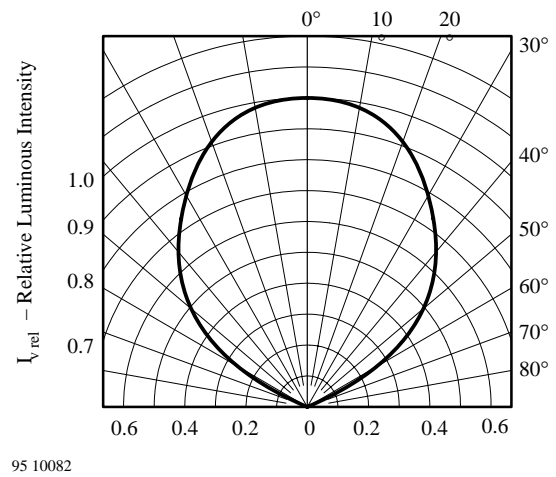


Figure 4 Rel. Luminous Intensity vs. Angular Displacement

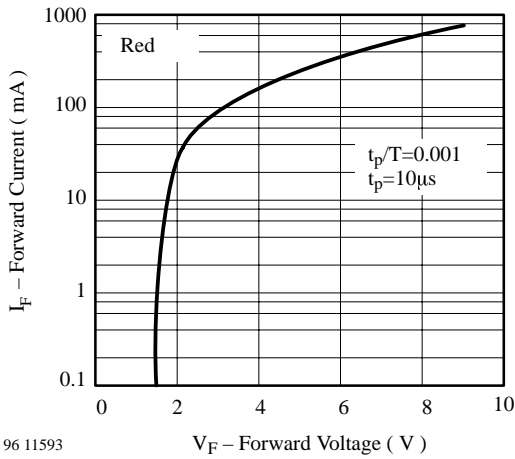


Figure 5 Forward Current vs. Forward Voltage

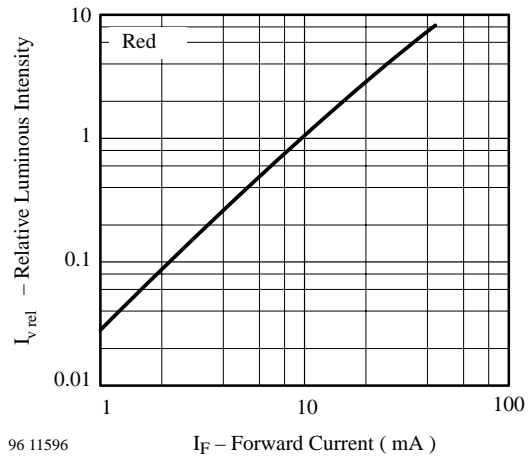


Figure 8 Relative Luminous Intensity vs. Forward Current

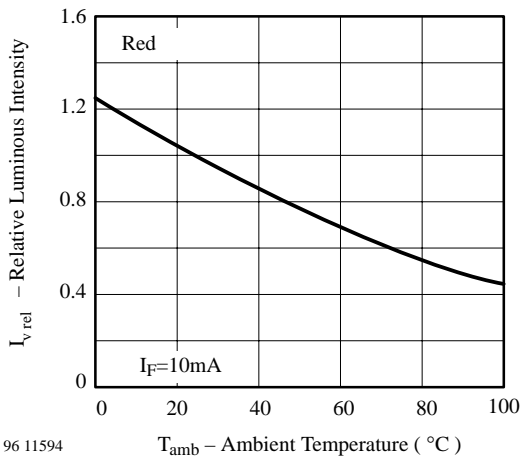


Figure 6 Rel. Luminous Intensity vs. Ambient Temperature

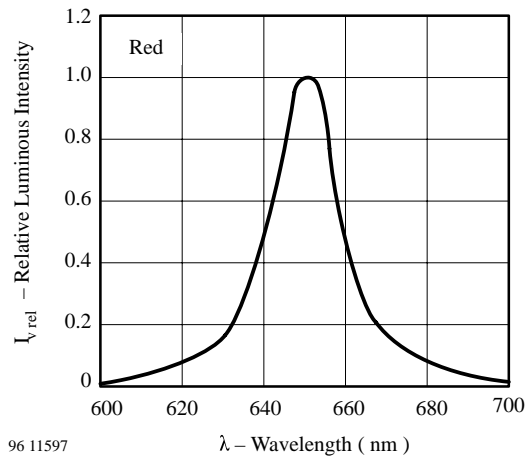


Figure 9 Relative Luminous Intensity vs. Wavelength

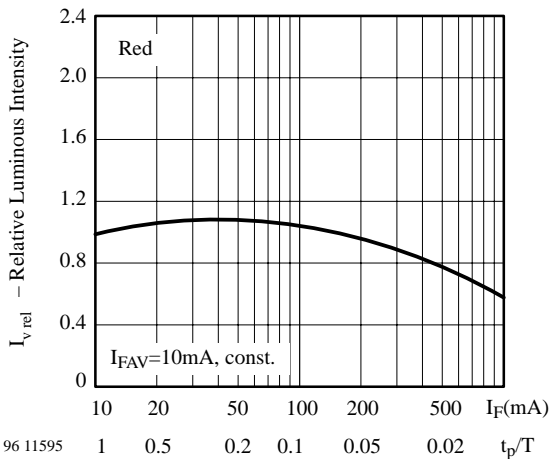


Figure 7 Rel. Lumin. Intensity vs. Forw. Current / Duty Cycle

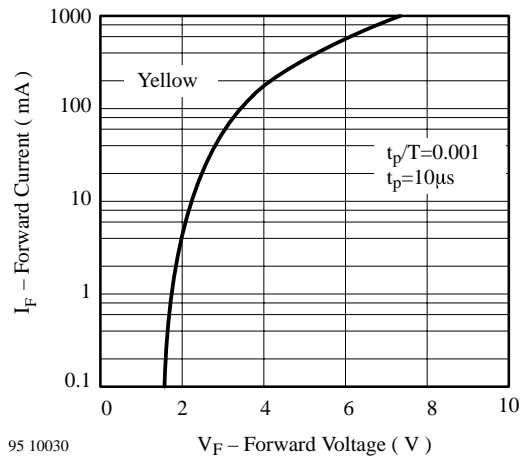
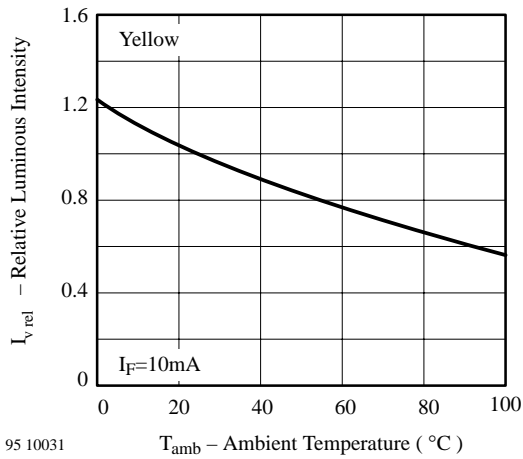
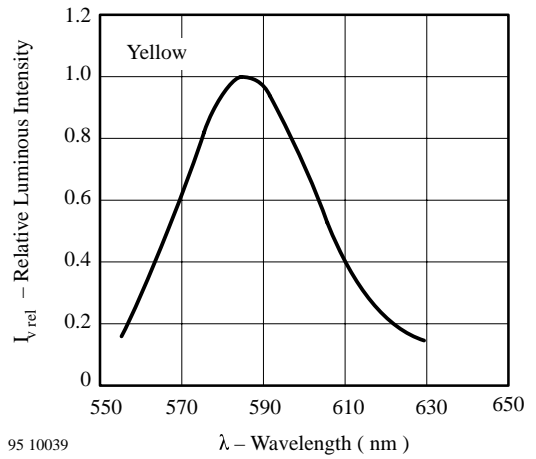


Figure 10 Forward Current vs. Forward Voltage



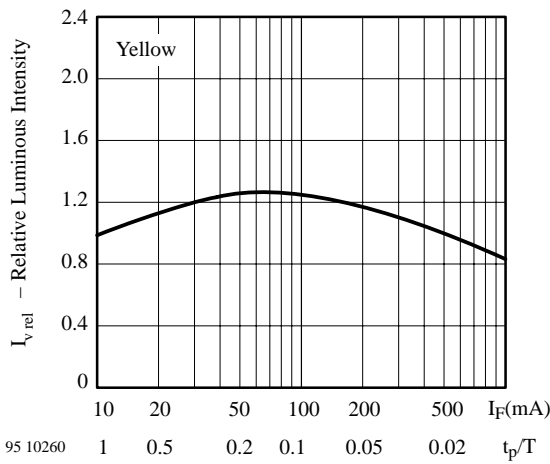
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Figure 11 Rel. Luminous Intensity vs Ambient Temperature



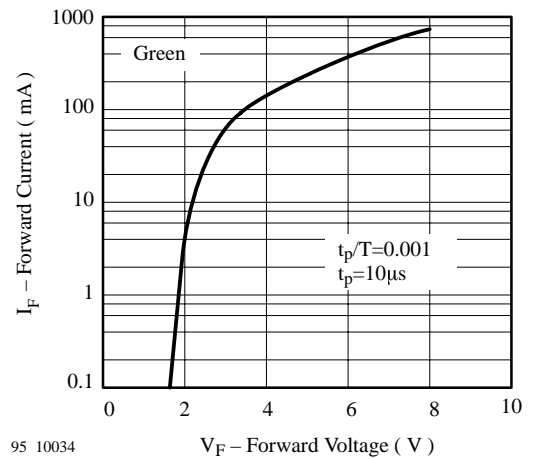
95 10039

Figure 14 Relative Luminous Intensity vs. Wavelength



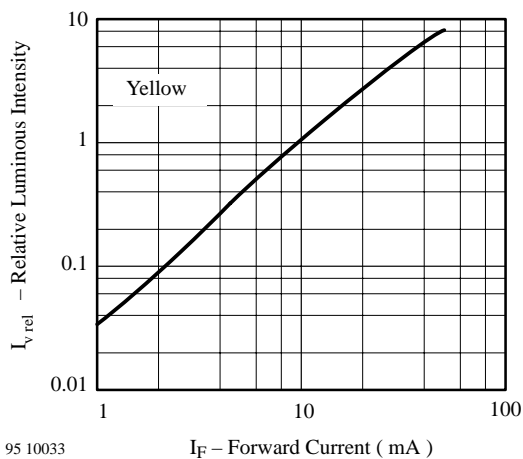
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Figure 12 Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle



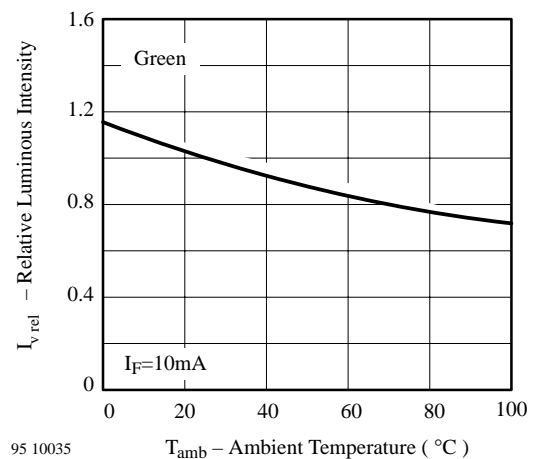
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Figure 15 Rel. Luminous Intensity vs. Ambient Temperature



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Figure 13 Relative Luminous Intensity vs. Forward Current



95 10035

Figure 16 Rel. Luminous Intensity vs. Ambient Temperature

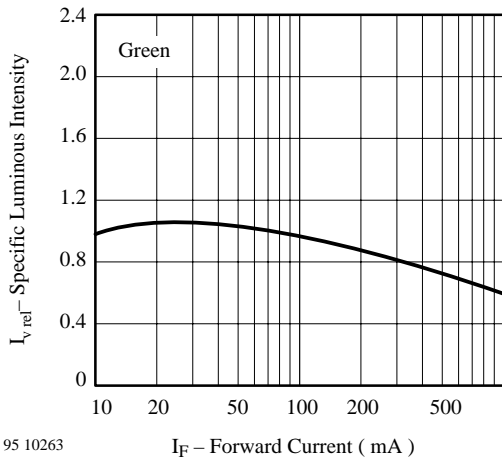


Figure 17 Specific Luminous Intensity vs. Forward Current

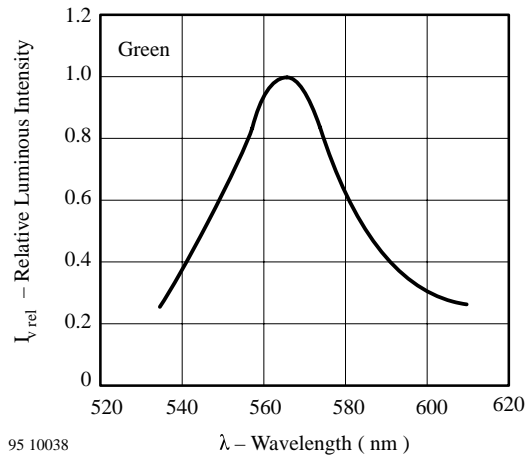


Figure 19 Relative Luminous Intensity vs. Wavelength

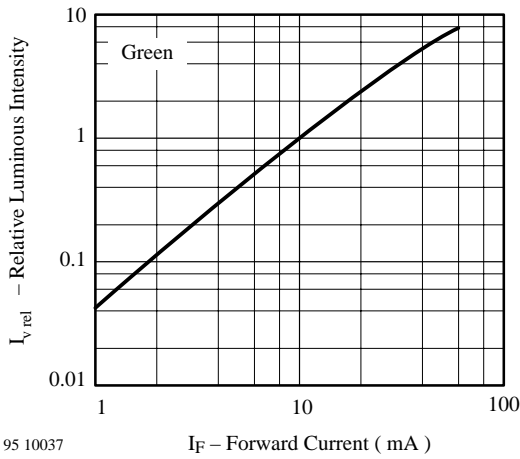
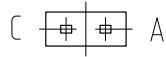
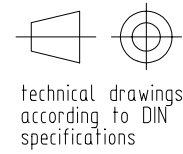
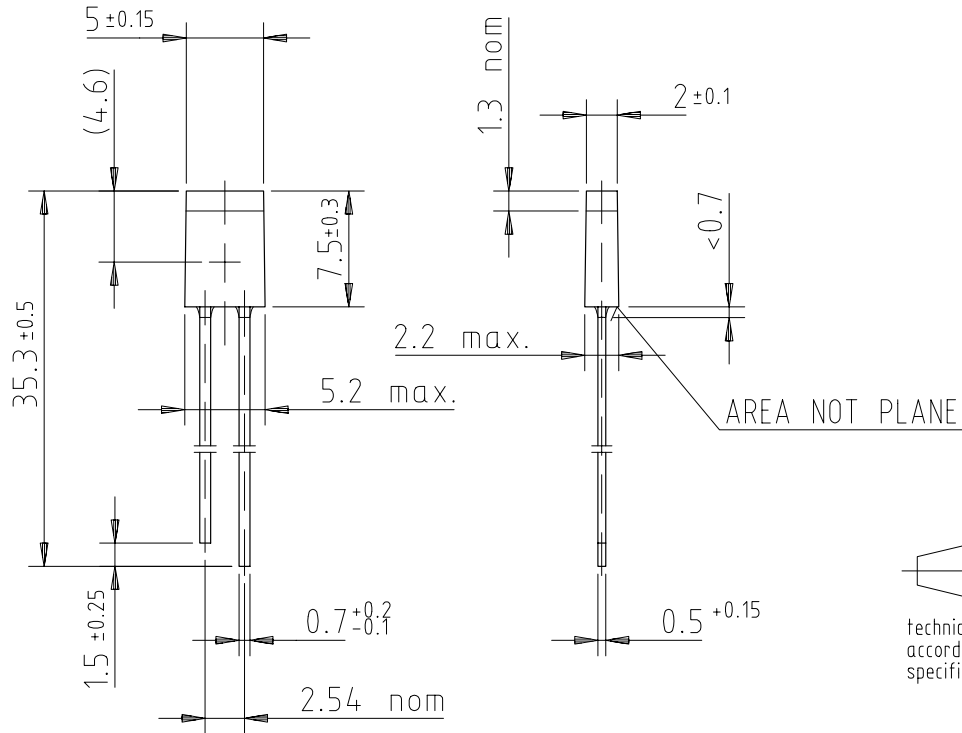


Figure 18 Relative Luminous Intensity vs. Forward Current

**Dimensions in mm**



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### Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**Vishay Semiconductor GmbH** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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